

United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE
United States Patent and Trademark Office
Address: COMMISSIONER FOR PATENTS
P.O. Box 1450
Alexandria, Virginia 22313-1450
www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
10/630,900	07/31/2003	Masanobu Nogome	2003_1075A	9620
513 75	7590 10/07/2004		EXAMINER	
WENDEROTH, LIND & PONACK, L.L.P.			TRAN, MAI HUONG C	
2033 K STREET N. W. SUITE 800		ART UNIT	PAPER NUMBER	
WASHINGTON, DC 20006-1021			2818	
			DATE MAILED: 10/07/2004	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)			
	10/630,900	NOGOME ET AL.			
Office Action Summary	Examiner	Art Unit			
	Mai-Huong Tran	2818			
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the co	orrespondence address			
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply If NO period for reply is specified above, the maximum statutory period we Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	66(a). In no event, however, may a reply be tim within the statutory minimum of thirty (30) days ill apply and will expire SIX (6) MONTHS from to cause the application to become ABANDONED	ely filed will be considered timely. the mailing date of this communication. (35 U.S.C. § 133).			
Status					
1) Responsive to communication(s) filed on 10 Se	eptember 2004.				
2a) ☐ This action is FINAL . 2b) ☑ This	<u> </u>				
Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.					
Disposition of Claims					
 4) ☐ Claim(s) 1-6 is/are pending in the application. 4a) Of the above claim(s) is/are withdraw 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 1-6 is/are rejected. 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction and/or 					
Application Papers					
9) The specification is objected to by the Examiner.					
10)⊠ The drawing(s) filed on 31 July 2003 is/are: a)□ accepted or b)⊠ objected to by the Examiner.					
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).					
Replacement drawing sheet(s) including the correcti 11) The oath or declaration is objected to by the Ex-		· ·			
Priority under 35 U.S.C. § 119					
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority documents 2. Certified copies of the priority documents 3. Copies of the certified copies of the priorical application from the International Bureau * See the attached detailed Office action for a list of	s have been received. s have been received in Application ity documents have been receive (PCT Rule 17.2(a)).	on No d in this National Stage			
Attachment(s)					
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948)	4) Interview Summary (PTO-413) Paper No(s)/Mail Date				
3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date 10/30/03.		atent Application (PTO-152)			

Application/Control Number: 10/630,900

Art Unit: 2818

DETAILED ACTION

Election/Restriction

Application's election without traverse of Group I (Claims 1-6) drawn to a semiconductor device is acknowledged for prosecution in the subject application. Accordingly, claims 7-16 are canceled.

Drawings

The drawings are objected to for the following reasons.

Figures 1A, 1B, and 1C are not designated by a legend such as "Prior Art". The Legend is necessary in order to clarify what applicant's invention is (see MPEP § 608.02g). Correction is required.

Claim Rejections - 35 U.S.C. § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claim 1 is rejected under 35 U. S. C. § 102 (b) as being anticipated by Applicant's admitted Prior Art (AAPA) (pages 1 and 2 of present specification and figures 1A-1C).

Regarding to claim 1, AAPA discloses a semiconductor device that includes a semiconductor substrate 100 having a via hole 140 that penetrates the semiconductor substrate 100 from a surface to a reverse side (fig 1B), wherein a part of an electrode (page 1, lines 31-32) formed on the surface of the semiconductor substrate 100 reaches the reverse side 150 of the semiconductor substrate 100 through the via hole 140, and an inside of the via hole 140 is filled in with a photosensitive resin (page 2, line 22, fig. 1C) to fully cover an aperture of the via hole 140 on the surface of the semiconductor substrate 100.

Claim Rejections - 35 U.S.C. § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 2-6 are rejected under 35 U.S.C. 103 (a) as being unpatentable over AAPA in view of U.S. Patent No. 5,528,074 to Goto et al. (hereinafter Goto) and further in view of Hayashi et al. (U.S. 4,902,726) (hereinafter Hayashi).

Application/Control Number: 10/630,900

Art Unit: 2818

Regarding to claim 2, AAPA discloses the claimed invention except for the semiconductor device wherein the photosensitive resin is filled in more shallowly than depth of the via hole.

However, Goto discloses the semiconductor device wherein the photosensitive resin 3b is filled in more shallowly than depth of the via hole (figs. 4(a)-4(e)).

It would have been obvious to one of ordinary skill in the art at the time the invention was made to form the semiconductor device wherein the photosensitive resin is filled in more shallowly than depth of the via hole, as taught by Goto in order to provide a semiconductor device operating at a microwave frequency that enables a reliable evaluation of input-output characteristics of the device and to provide a semiconductor device or a hybrid integrated circuit device that performs input and output of microwave signals with an external device without dissipation due to unwanted radiation and reflection (col. 4, lines 25-37).

Regarding to claims 3 and 5, AAPA in view of Goto discloses the claimed invention except for the semiconductor device wherein a main ingredient of the photosensitive resin is silicone resin or epoxy resin. However, Hayashi discloses a main ingredient of the photosensitive resin is epoxy resin (col. 1, lines 21-22, col. 5, lines 50-52).

It would have been obvious to one of ordinary skill in the art at the time the invention was made to form the main ingredient of the photosensitive resin to be epoxy

resin, as taught by Hayashi in order to provide a resin composition solution for obtaining a printed wiring board having high reliability with sufficient permanent mask film thickness at the upper portion of the circuit and around the through-hole on the substrate (col. 2, lines 40-44).

Regarding to claims 4 and 6, AAPA in view of Goto discloses the claimed invention except for the semiconductor device wherein viscosity of the photosensitive resin at 25°C is 70-600 mPas. However, Hayashi discloses the viscosity of the resin composition solution is 500 to 1200 mPas, 200 to 700 mPas (col. 2, lines 10-15), and the composition solution has a viscosity at 25°C of 100 mPas or more and 200 mPas or less (col. 2, lines 58-60). Although the Hayashi ranges are slightly different from the claimed range, this does not define patentable over AAPA in view of Goto and further in view of Hayashi since the discovery of the optimum or workable range involves only routine skill in the art. In re Aller, 105 USPQ 233.

Art Unit: 2818

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Mai-Huong Tran whose telephone number is (571)272-1796. The examiner can normally be reached on 8:00-4:30.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, David Nelms can be reached on (571)272-1787. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Mai-Huong Tran

Examiner

Art Unit 2818